TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

4N29(Short), 4N29A(Short), 4N30(Short), 4N31(Short) 4N32(Short), 4N32A(Short), 4N33(Short)

AC LINE/DIGITAL LOGIC ISOLATOR. DIGITAL LOGIC/DIGITAL LOGIC ISOLATOR. TELEPHONE LINE RECEIVER. TWISTED PAIR LINE RECEIVER. RELAY CONTACT MONITOR.

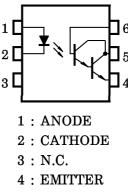
The TOSHIBA 4N29 (Short) through 4N33 (Short) consists arsenide infrared emitting diode coupled with a silicon photo darlington in a dual in-line package.

- Switching Time :  $100\mu s$  (Max.)
- DC Current Transfer Ratio : 500%
- Isolation Resistance :  $10^{11}\Omega$  (Typ.)
- Isolation Voltage : 2500V<sub>rms</sub> (Min.)
- UL Recognized
- : UL1577, File No. E67349

 $6.4 \pm 0.25$ <u>二</u> 2 Т З 65 +0.15 7.12 ± 0.25 7.62 ± 0.25 0.25 0.8 ± 0 0.25-0.05 1.2 ± 0.15 WWS .25 0.5 ± 0. 7.85~8.80 2.54 ± 0.25 11-7A8 TOSHIBA 11-7A8

Weight : 0.4g

PIN CONFIGURATIONS (Top view)



- 5 : COLLECTOR
- 6 : BASE

Unit in mm

## MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
LED	Forward Current (Continuous)	IF	80	mA
	Forward Current Derating	⊿I <sub>F</sub> /°C	1.07(*)	mA/°C
	Peak Forward Current (Note 1)	I <sub>PF</sub>	3	Α
	Power Dissipation	PD	150	mW
	Power Dissipation Derating	$\Delta P_D / C$	2.0(*)	mW/°C
	Reverse Voltage	VR	3	V
Я	Collector-Emitter Voltage	BVCEO	30	V
ΤO	Collector-Base Voltage	BVCBO	30	V
5	Emitter-Collector Voltage	BVECO	5	V
田	Collector Current (Continuous)	IC	100	mA
ΕŢ	Power Dissipation	PC	150	mW
D	Power Dissipation Derating	⊿PC/°C	2.0(*)	mW/°C
A	Storage Temperature Range	T <sub>stg</sub>	$-55 \sim 150$	°C
COUPLEI	Operating Temperature Range	T <sub>opr</sub>	$-55 \sim 100$	°C
	Lead Soldering Temperature	T <sub>sol</sub>	260	°C
	Total Package Power Dissipation	PT	250	mW
	Total Package Power Dissipation Derating	ΔP <sub>T</sub> /°C	3.3(*)	mW/°C

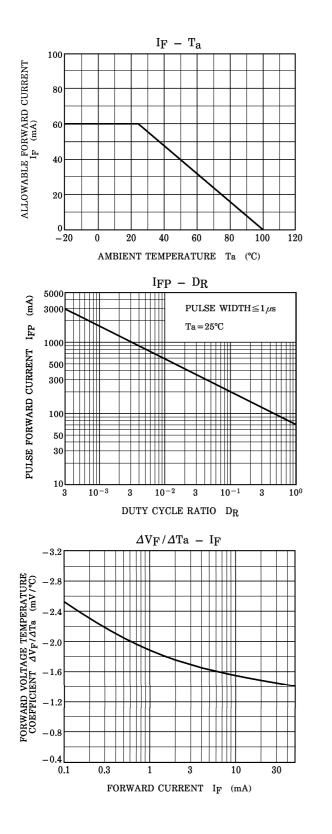
(Note 1) Pulse width  $300\mu s$ , 2% duty cycle.

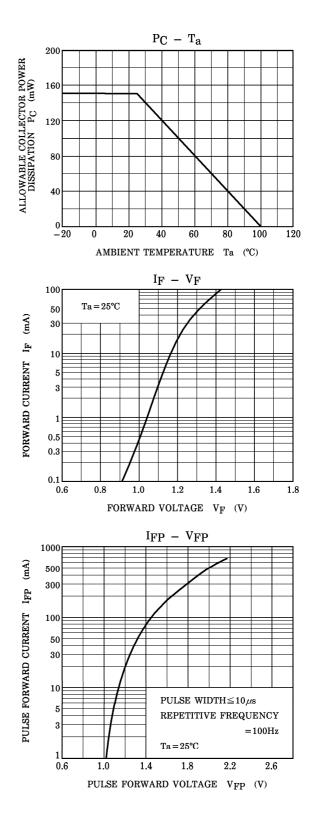
(\*) Above 25°C ambient.

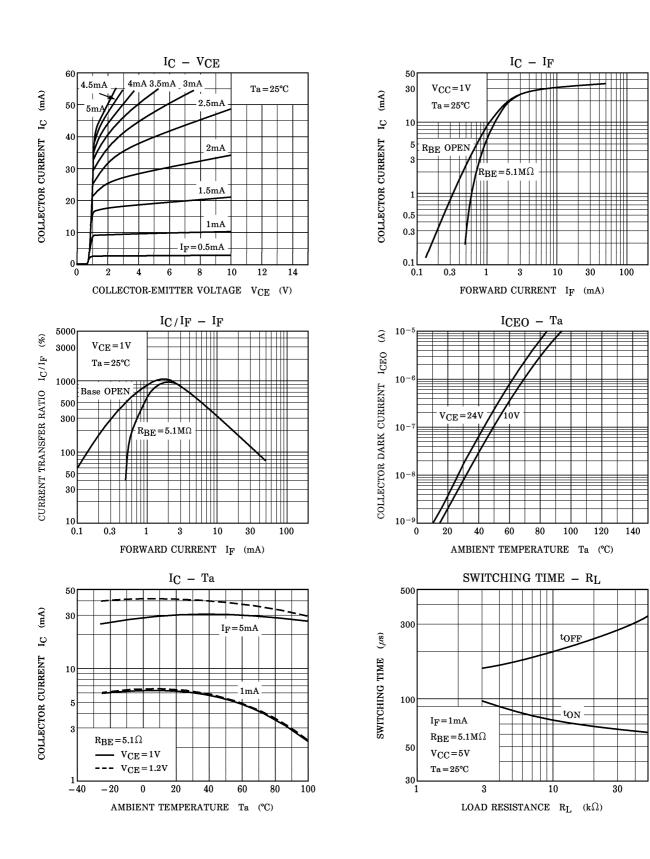
ELECTRICAL	CHARACTERISTICS	(Ta = 25°C)
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CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Q	Forward Voltage		V <sub>F</sub>	$I_F = 10 mA$	—	1.15	1.5	V
LEI	Reverse Current		IR	V <sub>R</sub> =3V	—		100	μA
	Capacitance		CD	V=0, f=1MHz	—	30	—	pF
DETECTOR	DC Forward Current Gain		hFE	$V_{CE} = 5, I_C = 0.5 mA$	—	10k	—	_
	Collector-Emitter Breakdown Voltage		V (BR) CEO	$I_{C} = 1 m A$	30	_	-	v
	Collector-Base Breakdown Voltage		V (BR) CBO	$I_{C} = 100 \mu A$	30	_	-	v
	Emitter-Collector Breakdown Voltage		V (BR) ECO	$I_{E} = 100 \mu A$	5	_	_	v
	Collector Dark Current		ICEO	V <sub>CE</sub> =10V	—	1.0	100	nA
	Collector Output Current	4N32, 4N32A 4N33	I <sub>C</sub>	$I_F = 10 \text{mA}, V_{CE} = 10 \text{V}$	50	_	_	mA
		4N29, 4N29A 4N30			10	_	_	
		4N31			5		_	
	Collector- Emitter Saturation	4N29, 4N29A 4N30, 4N32 4N32A, 4N33	V <sub>CE (sat)</sub>	$I_F = 8mA$ , $I_C = 2mA$	_	_	1.0	v
	Voltage	4N31			<u> </u>		1.2	
A	Turn-on Time		ton				5	μs
COUPLE	Turn-off Time	4N29, 4N29A 4N30, 4N31 4N32, 4N32A	tOFF	$I_{F} = 200 \text{mA}, V_{CC} = 10 \text{V}$ $I_{C} = 50 \text{mA}$	_	_	40 100	μs
	4N33						<b> </b>	
	Capacitance Input to Output		CS	V=0, f=1MHz	_	0.8	—	pF
	Isolation Resistance		RS	V = 500V	—	1011	—	Ω
			BVS	AC, 1 minute R. H. $\leq 60\%$	2500	-	<u> </u>	V <sub>rms</sub>
	Isolation Voltage	4N29, 4N29A 4N32, 4N32A	BV <sub>S</sub> (*)	AC, peak	2500	_	_	Vala
		4N30, 4N31 4N33			1500	_	_	Vpk
		4N29A, 4N32A	<u> </u>	AC, 1 second	1775	_	_	V <sub>rms</sub>

(\*) JEDEC registered minimum BVS, however, Toshiba specifies a minimum BVS of  $2500 \rm V_{rms}$  1 minute.







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